NSN 5961-01-033-3079

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Inclosure Material:

Metal

Overall Length:

Between 1.479 inches and 1.519 inches

Overall Height:

Between 0.250 inches and 0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage, dc and 60.0 breakdown voltage, collector-to-emitter, base open and 70.0 collector to emitter reverse voltage and 7.0 emitter to base voltage, dc

Current Rating Per Characteristic:

Between 7.00 amperes source cutoff current and 15.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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